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FDB088N08

N-Channel PowerTrench® MOSFET

75 V, 85 A, 8.8 mΩ



Features

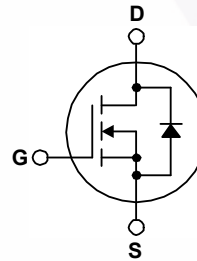
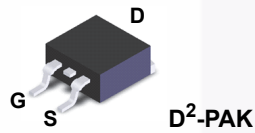
- $R_{DS(on)} = 7.3 \text{ m}\Omega$ (Typ.) @ $V_{GS} = 10 \text{ V}$, $I_D = 75 \text{ A}$
- Fast Switching Speed
- Low Gate Charge
- High Performance Trench Technology for Extremely Low $R_{DS(on)}$
- High Power and Current Handling Capability
- 100% Internal R_G Screening for Easy Paralleling Operation
- RoHS Compliant

Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench® process that has been tailored to minimize the on-state resistance while maintaining superior switching performance.

Applications

- Synchronous Rectification for ATX / Server / Telecom PSU
- Battery Protection Circuit
- Motor Drives and Uninterruptible Power Supplies



Absolute Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted.

| Symbol | Parameter | FDB088N08 | Unit |
|----------------|--|---|------------------|
| V_{DSS} | Drain to Source Voltage | 75 | V |
| V_{GSS} | Gate to Source Voltage | ± 20 | V |
| I_D | Drain Current | - Continuous ($T_C = 25^\circ\text{C}$, Silicon Limited) | 85 |
| | | - Continuous ($T_C = 100^\circ\text{C}$, Silicon Limited) | 60 |
| | | - Continuous ($T_C = 25^\circ\text{C}$, Package Limited) | 120 |
| I_{DM} | Drain Current - Pulsed (Note 1) | 340 | A |
| E_{AS} | Single Pulsed Avalanche Energy (Note 2) | 309 | mJ |
| dv/dt | Peak Diode Recovery dv/dt (Note 3) | 10 | V/ns |
| P_D | Power Dissipation | ($T_C = 25^\circ\text{C}$) | 160 |
| | | - Derate above 25°C | 1.06 |
| T_J, T_{STG} | Operating and Storage Temperature Range | -55 to +175 | $^\circ\text{C}$ |
| T_L | Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds | 300 | $^\circ\text{C}$ |

Thermal Characteristics

| Symbol | Parameter | FDB088N08 | Unit |
|-----------------|--|-----------|---------------------------|
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case, Max. | 0.94 | $^\circ\text{C}/\text{W}$ |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient (Minimum Pad of 2-oz Copper), Max. | 62.5 | |
| | Thermal Resistance, Junction to Ambient (1 in ² Pad of 2-oz Copper), Max. | 40 | |

Package Marking and Ordering Information

| Part Number | Top Mark | Package | Packing Method | Reel Size | Tape Width | Quantity |
|-------------|-----------|---------------------|----------------|-----------|------------|-----------|
| FDB088N08 | FDB088N08 | D ² -PAK | Tape and Reel | 330 mm | 24 mm | 800 units |

Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted.

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|--------|-----------|-----------------|------|------|------|------|
|--------|-----------|-----------------|------|------|------|------|

Off Characteristics

| | | | | | | |
|--------------------------------|---|---|----|------|-----------|---------------------|
| BV_{DSS} | Drain to Source Breakdown Voltage | $I_D = 250 \mu\text{A}$, $V_{GS} = 0 \text{ V}$, $T_C = 25^\circ\text{C}$ | 75 | - | - | V |
| $\Delta BV_{DSS} / \Delta T_J$ | Breakdown Voltage Temperature Coefficient | $I_D = 250 \mu\text{A}$, Referenced to 25°C | - | 0.07 | - | V/ $^\circ\text{C}$ |
| I_{DSS} | Zero Gate Voltage Drain Current | $V_{DS} = 75 \text{ V}$, $V_{GS} = 0 \text{ V}$ | - | - | 1 | μA |
| | | $V_{DS} = 75 \text{ V}$, $T_C = 150^\circ\text{C}$ | - | - | 500 | |
| I_{GSS} | Gate to Body Leakage Current | $V_{GS} = \pm 20 \text{ V}$, $V_{DS} = 0 \text{ V}$ | - | - | ± 100 | nA |

On Characteristics

| | | | | | | |
|--------------|--------------------------------------|--|-----|-----|-----|------------|
| $V_{GS(th)}$ | Gate Threshold Voltage | $V_{GS} = V_{DS}$, $I_D = 250 \mu\text{A}$ | 2.0 | - | 4.0 | V |
| $R_{DS(on)}$ | Static Drain to Source On Resistance | $V_{GS} = 10 \text{ V}$, $I_D = 75 \text{ A}$ | - | 7.3 | 8.8 | m Ω |
| g_{FS} | Forward Transconductance | $V_{DS} = 10 \text{ V}$, $I_D = 37.5 \text{ A}$ | - | 300 | - | S |

Dynamic Characteristics

| | | | | | | |
|--------------|-------------------------------|---|----------|------|------|----------|
| C_{iss} | Input Capacitance | $V_{DS} = 25 \text{ V}$, $V_{GS} = 0 \text{ V}$, $f = 1 \text{ MHz}$ | - | 4960 | 6595 | pF |
| C_{oss} | Output Capacitance | | - | 355 | 470 | pF |
| C_{rss} | Reverse Transfer Capacitance | | - | 200 | 300 | pF |
| $Q_{g(tot)}$ | Total Gate Charge at 10V | $V_{DS} = 60 \text{ V}$, $I_D = 75 \text{ A}$, $V_{GS} = 10 \text{ V}$ | - | 91 | 118 | nC |
| Q_{gs} | Gate to Source Gate Charge | | - | 22 | - | nC |
| Q_{gd} | Gate to Drain "Miller" Charge | | (Note 4) | - | 28 | - |
| R_G | Gate Resistance | $f = 1 \text{ MHz}$ | - | - | 4 | Ω |

Switching Characteristics

| | | | | | | |
|--------------|---------------------|---|----------|-----|-----|-----|
| $t_{d(on)}$ | Turn-On Delay Time | $V_{DD} = 37.5 \text{ V}$, $I_D = 75 \text{ A}$, $R_G = 25 \Omega$, $V_{GS} = 10 \text{ V}$ | - | 45 | 100 | ns |
| t_r | Turn-On Rise Time | | - | 158 | 326 | ns |
| $t_{d(off)}$ | Turn-Off Delay Time | | - | 244 | 498 | ns |
| t_f | Turn-Off Fall Time | | (Note 4) | - | 102 | 214 |

Drain-Source Diode Characteristics

| | | | | | | |
|----------|--|--|---|------|------|----|
| I_S | Maximum Continuous Drain to Source Diode Forward Current | - | - | 85 | A | |
| I_{SM} | Maximum Pulsed Drain to Source Diode Forward Current | - | - | 340 | A | |
| V_{SD} | Drain to Source Diode Forward Voltage | $V_{GS} = 0 \text{ V}$, $I_{SD} = 75 \text{ A}$ | - | - | 1.25 | V |
| t_{rr} | Reverse Recovery Time | $V_{GS} = 0 \text{ V}$, $I_{SD} = 75 \text{ A}$, | - | 41.1 | - | ns |
| Q_{rr} | Reverse Recovery Charge | $di_F/dt = 100 \text{ A}/\mu\text{s}$ | - | 80.7 | - | nC |

Notes:

1. Repetitive rating: pulse-width limited by maximum junction temperature.
2. $L = 0.11 \text{ mH}$, $I_{AS} = 75 \text{ A}$, $V_{DD} = 50 \text{ V}$, $R_G = 25 \Omega$, starting $T_J = 25^\circ\text{C}$.
3. $I_{SD} \leq 75 \text{ A}$, $di/dt \leq 200 \text{ A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, starting $T_J = 25^\circ\text{C}$.
4. Essentially independent of operating temperature typical characteristics.

Typical Performance Characteristics

Figure 1. On-Region Characteristics

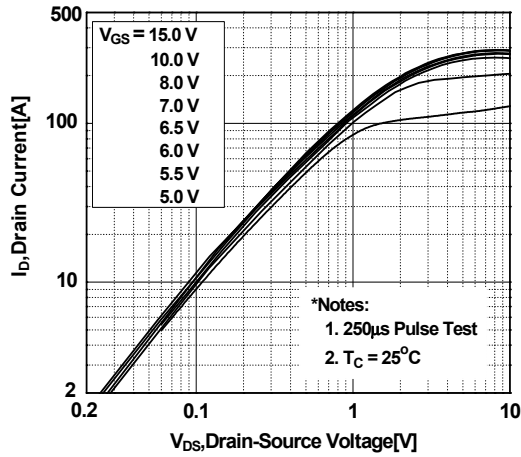


Figure 2. Transfer Characteristics

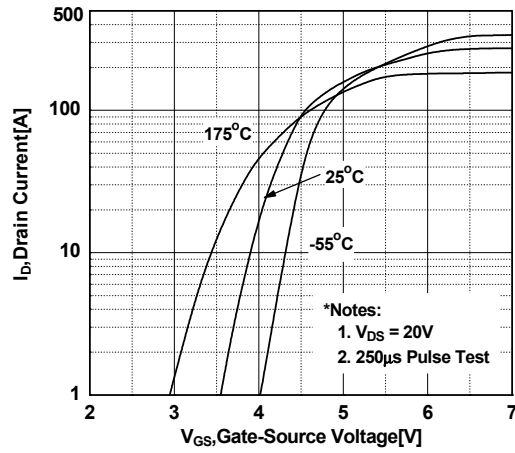


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

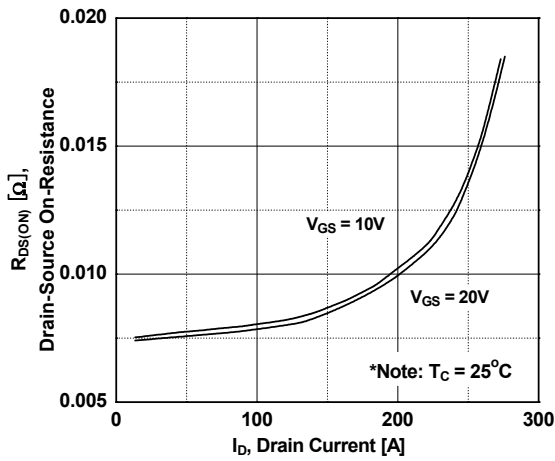


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

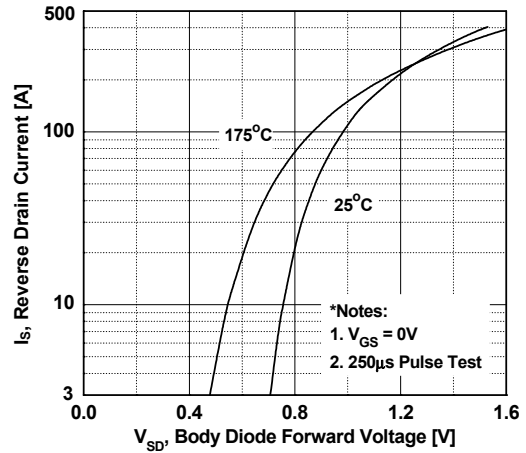


Figure 5. Capacitance Characteristics

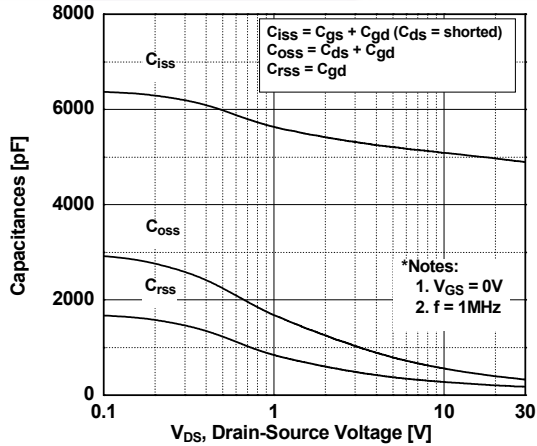
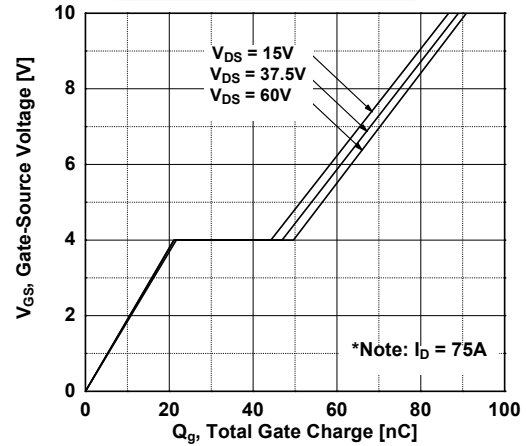


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

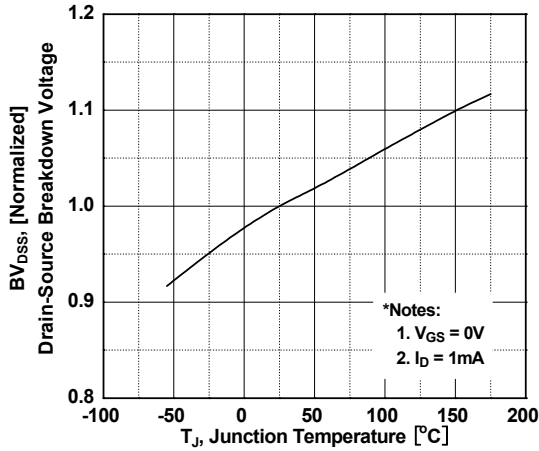


Figure 8. On-Resistance Variation vs. Temperature

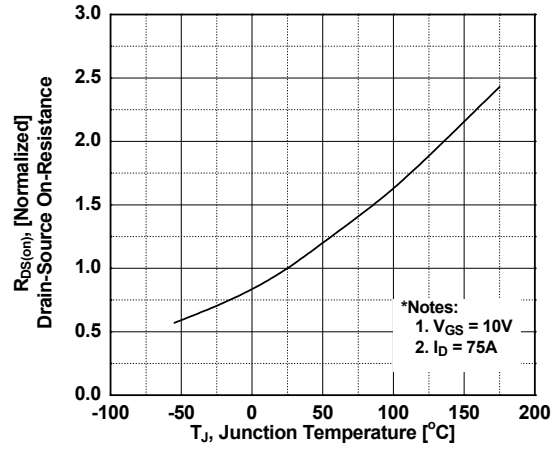


Figure 9. Maximum Safe Operating Area

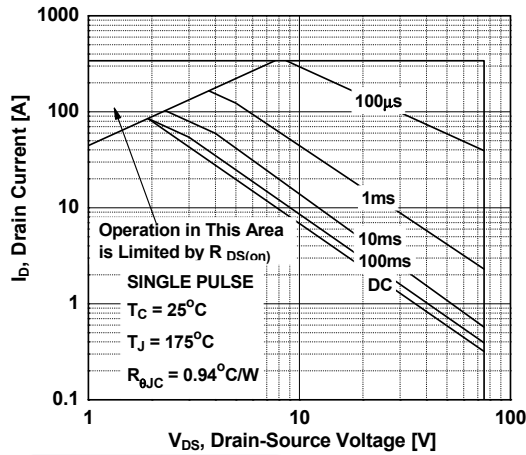


Figure 10. Maximum Drain Current vs. Case Temperature

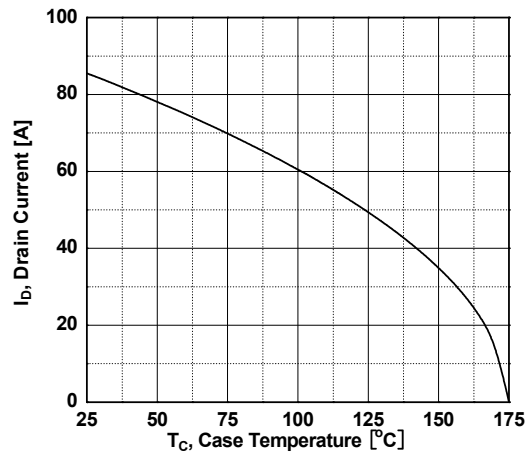


Figure 11. Transient Thermal Response Curve

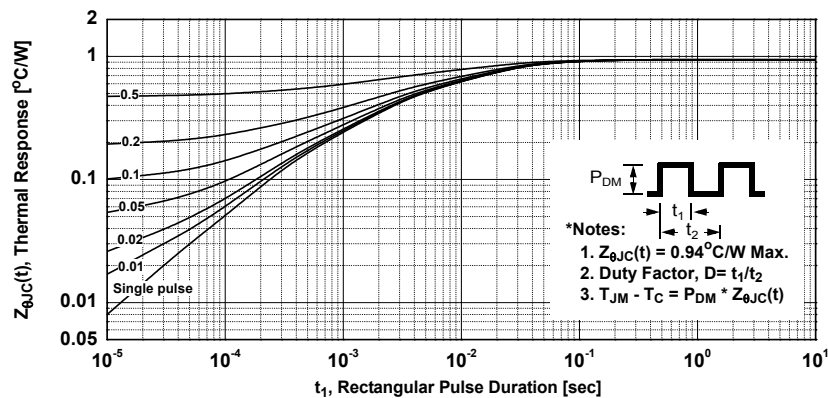




Figure 12. Gate Charge Test Circuit & Waveform



Figure 13. Resistive Switching Test Circuit & Waveforms



Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms



Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms

Mechanical Dimensions

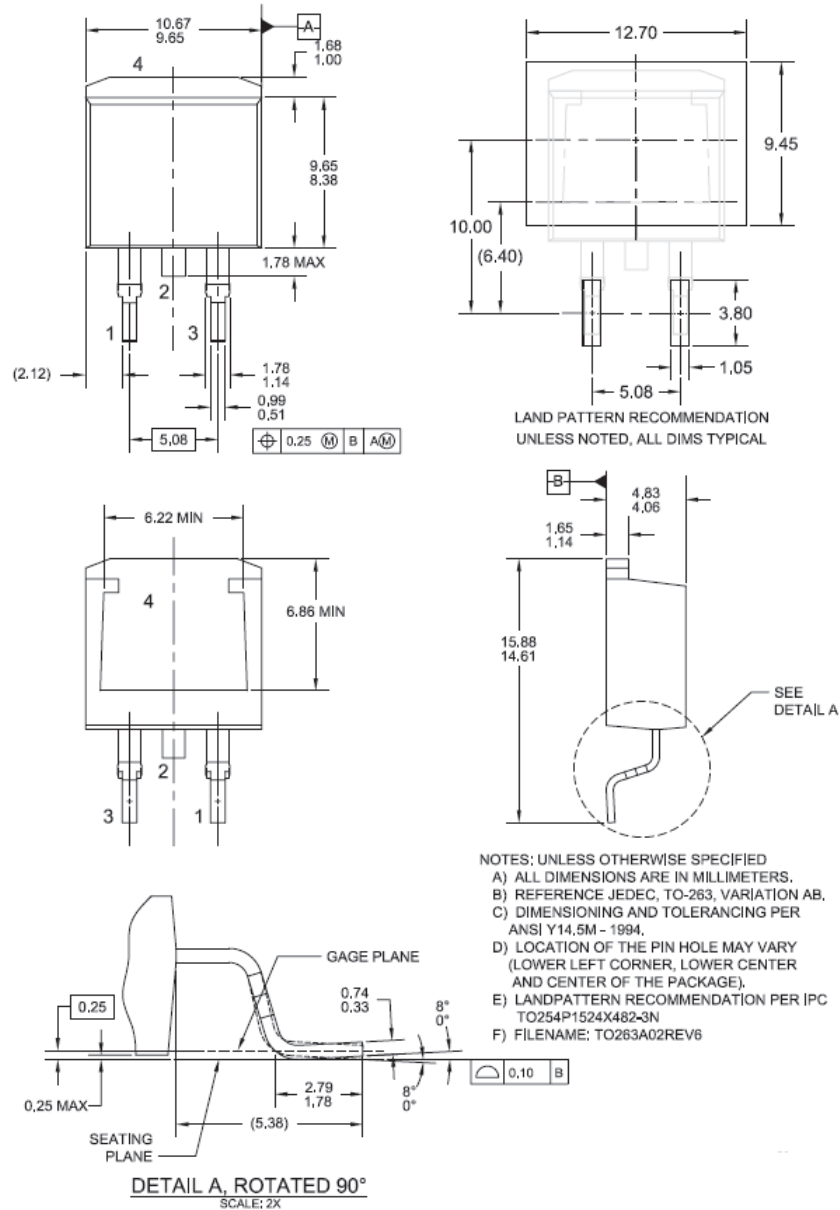


Figure 16. TO263 (D²PAK), Molded, 2-Lead, Surface Mount

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